# NSN 5961-00-710-8119

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Inclosure Material:

Metal

**Overall Length:** 

0.250 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-emitter, base open and 1.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current

## Power Rating Per Characteristic:

60.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## Terminal Type And Quantity:

2 tab, solder lug and 1 case

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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